74ALVT162821

20-bit bus interface D-type flip-flop; positive-edge trigger with 30 Ω termination resistors; 3-state

Rev. 6 — 25 June 2024

Product data sheet

1. General description

The 74ALVT162821 is a 20-bit positive-edge triggered D-type flip-flop with 30 Ω termination resistors and 3-state outputs

The device can be used as two 10-bit flip-flops or one 20-bit flip-flop. The device features two clocks (1CP and 2CP) and two output enables (1OE and 2OE), each controlling 10-bits. The flip-flops will store the state of their individual D-inputs that meet the set-up and hold time requirements on the LOW-to-HIGH clock (nCP) transition. A HIGH on nOE causes the outputs to assume a high-impedance OFF-state. Operation of the nOE input does not affect the state of the flip-flops. Bus hold data inputs eliminate the need for external pull-up resistors to define unused inputs

2. Features and benefits

- Wide supply voltage range from 2.3 V to 3.6 V
- Overvoltage tolerant inputs to 5.5 V
- · BiCMOS high speed and output drive
- Outputs include series resistance of 30 Ω making external termination resistors unnecessary
- No bus current loading when output is tied to 5 V bus
- · Direct interface with TTL levels
- I_{OFF} circuitry provides partial Power-down mode operation
- · 20-bit positive-edge triggered register
- 5 V I/O compatible
- Multiple V_{CC} and GND pins minimize switching noise
- Bus hold on data inputs
- Live insertion and extraction permitted
- Power-up reset
- · Power-up 3-state
- Output capability: +12 mA and -12 mA
- Latch-up protection:
 - JESD17: exceeds 500 mA
- ESD protection:
 - HBM: ANSI/ESDA/JEDEC JS-001 class 2 exceeds 2000 V
 - CDM: ANSI/ESDA/JEDEC JS-002 class C3 exceeds 1000 V
- Specified from -40 °C to 85 °C

3. Ordering information

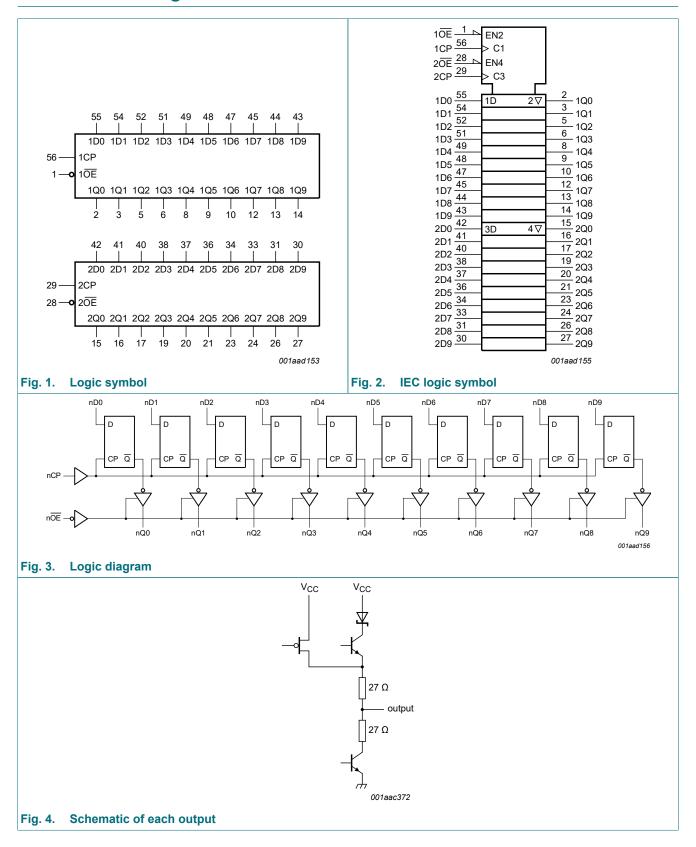
Table 1. Ordering information

Туре	number	Package			
		Temperature range	Name	Description	Version
74AL	VT162821DGG	-40 °C to +85 °C	TSSOP56	plastic thin shrink small outline package; 56 leads; body width 6.1 mm	SOT364-1



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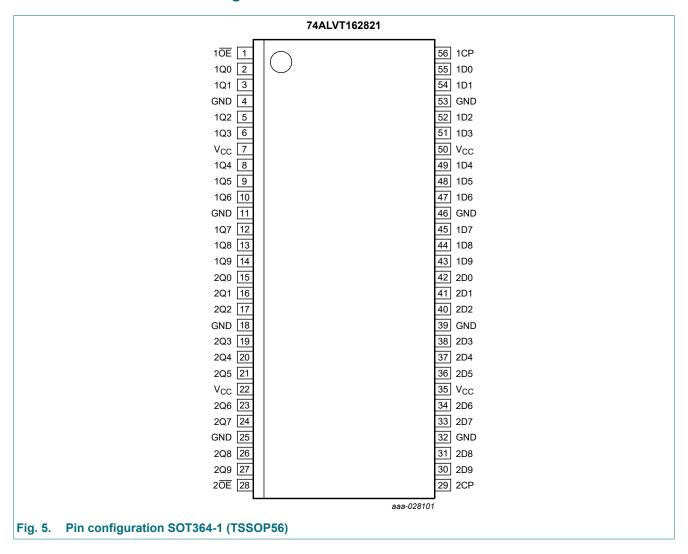
4. Functional diagram



20-bit bus interface D-type flip-flop; positive-edge trigger with 30 Ω termination resistors; 3-state

5. Pinning information

5.1. Pinning



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5.2. Pin description

Table 2. Pin description

Symbol	Pin	Description
1D0, 1D1, 1D2, 1D3, 1D4, 1D5, 1D6, 1D7, 1D8, 1D9	55, 54, 52, 51, 49, 48, 47, 45, 44, 43	data inputs
1Q0, 1Q1, 1Q2, 1Q3, 1Q4, 1Q5, 1Q6, 1Q7, 1Q8, 1Q9	2, 3, 5, 6, 8, 9, 10, 12, 13, 14	data outputs
2D0, 2D1, 2D2, 2D3, 2D4, 2D5, 2D6, 2D7, 2D8, 2D9	42, 41, 40, 38, 37, 36, 34, 33, 31, 30	data inputs
2Q0, 2Q1, 2Q2, 2Q3, 2Q4, 2Q5, 2Q6, 2Q7, 2Q8, 2Q9	15, 16, 17, 19, 20, 21, 23, 24, 26, 27	data outputs
10E, 20E	1, 28	output enable inputs (active LOW)
1CP, 2CP	56, 29	clock pulse inputs (active rising edge)
GND	4, 11, 18, 25, 32, 39, 46, 53	ground (0 V)
V _{CC}	7, 22, 35, 50	supply voltage

6. Functional description

Table 3. Function table

H = HIGH voltage level; h = HIGH voltage level one set-up time prior to the LOW-to-HIGH clock transition;

L = LOW voltage level; I = LOW voltage level one set-up time prior to the LOW-to-HIGH clock transition;

NC = no change; X = don't care;

 $Z = high-impedance OFF-state; \uparrow = LOW-to-HIGH clock transition.$

Operating mode	Input			Internal register	Output
	nOE	nCP	nDn		nQn
Load and read register	L	1	I	L	L
	L	1	h	Н	Н
Hold	L	NC	X	NC	NC
Disable outputs	Н	NC	X	NC	Z
	Н	1	nDn	nDn	Z

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7. Limiting values

Table 4. Limiting values

In accordance with the Absolute Maximum Rating System (IEC 60134).

Symbol	Parameter	Conditions	Min	Max	Unit
V _{CC}	supply voltage		-0.5	+4.6	V
VI	input voltage	[1]	-1.2	+7.0	V
Vo	output voltage	output in OFF-state or HIGH-state [1]	-0.5	+7.0	V
I _{IK}	input clamping current	V _I < 0 V	-	-50	mA
I _{OK}	output clamping current	V _O < 0 V	-	-50	mA
Io	output current	output in LOW-state	-	128	mA
		output in HIGH-state	-	-64	mA
T _{stg}	storage temperature		-65	+150	°C
Tj	junction temperature	[2]	-	150	°C

^[1] The input and output negative voltage ratings may be exceeded if the input and output clamp current ratings are observed.

8. Recommended operating conditions

Table 5. Recommended operating conditions

Symbol	Parameter	Conditions	V _{CC} = 2.5	V ± 0.2 V	V _{CC} = 3.3	Unit	
			Min	Max	Min	Max	
V _{CC}	supply voltage		2.3	2.7	3.0	3.6	V
VI	input voltage		0	5.5	0	5.5	V
I _{OH}	HIGH-level output current		-	-8	-	-12	mA
I _{OL}	LOW-level output current	none	-	12	-	12	mA
Δt/ΔV	input transition rise and fall rate	outputs enabled	-	10	-	10	ns/V
T _{amb}	ambient temperature	free-air	-40	+85	-40	+85	°C

9. Static characteristics

Table 6. Static characteristics

At recommended operating conditions; T_{amb} = -40 °C to +85 °C; voltages are referenced to GND (ground = 0 V).

Symbol	Parameter	Conditions	Min	Typ[1]	Max	Unit
V _{CC} = 2.	5 V ± 0.2 V					
V _{IK}	input clamping voltage	V _{CC} = 2.3 V; I _{IK} = -18 mA	-	-0.85	-1.2	V
V_{IH}	HIGH-level input voltage		1.7	-	-	V
V_{IL}	LOW-level input voltage		-	-	0.7	V
V _{OH}	HIGH-level output voltage	V_{CC} = 2.3 V to 3.6 V; I_{O} = -100 μA	V _{CC} - 0.2	V _{CC}	-	V
		$V_{CC} = 2.3 \text{ V; I}_{O} = -8 \text{ mA}$	1.8	2.1	-	V
V_{OL}	LOW-level output voltage	$V_{CC} = 2.3 \text{ V}; I_{O} = 100 \mu\text{A}$	-	0.07	0.2	V
		$V_{CC} = 2.3 \text{ V; I}_{O} = 24 \text{ mA}$	-	0.3	0.5	V
		V _{CC} = 2.3 V; I _O = 8 mA	-	-	0.4	V
V _{OL(pu)}	power-up LOW-level output voltage	$V_{CC} = 2.7 \text{ V}; I_O = 1 \text{ mA}; V_I = V_{CC} \text{ or GND}$ [2]	-	-	0.55	V

^[2] The performance capability of a high-performance integrated circuit in conjunction with its thermal environment can create junction temperatures which are detrimental to reliability.

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Symbol	Parameter	Conditions	Min	Typ[1]	Max	Unit
I _I	input leakage current	all input pins				
		V _{CC} = 0 V or 2.7 V; V _I = 5.5 V	-	0.1	10	μΑ
		control pins				
		$V_{CC} = 2.7 \text{ V}; V_I = V_{CC} \text{ or GND}$	-	0.1	±1	μA
		data pins; [3]				
		$V_{CC} = 2.7 \text{ V}; V_{I} = V_{CC}$	-	0.1	1	μA
		V _{CC} = 2.7 V; V _I = 0 V	-	0.1	-5	μA
I _{OFF}	power-off leakage current	$V_{CC} = 0 \text{ V}; V_{I} \text{ or } V_{O} = 0 \text{ V to } 4.5 \text{ V}$	-	0.1	±100	μA
I _{BHL}	bus hold LOW current	data inputs; $V_{CC} = 2.3 \text{ V}$; $V_I = 0.7 \text{ V}$	-	90	-	μA
I _{BHH}	bus hold HIGH current	data inputs; $V_{CC} = 2.3 \text{ V}$; $V_I = 1.7 \text{ V}$	-	-10	-	μA
I _{EX}	external current	output in HIGH-state when $V_O > V_{CC}$; $V_O = 5.5 \text{ V}; V_{CC} = 2.3 \text{ V}$	-	10	125	μA
I _{O(pu/pd)}	power-up/power-down output current	$V_{CC} \le 1.2 \text{ V}; V_O = 0.5 \text{ V to } V_{CC};$ $V_I = \text{GND or } V_{CC}; \text{ n} \overline{\text{OE}} = \text{don't care}$	-	1	±100	μΑ
I _{OZ}	OFF-state output current	$V_{CC} = 2.7 \text{ V}; V_I = V_{IL} \text{ or } V_{IH}$				
		output HIGH-state; V _O = 2.3 V	-	0.5	5	μA
		output LOW-state; V _O = 0.5 V	-	0.5	-5	μΑ
I _{CC}	supply current	$V_{CC} = 2.7 \text{ V}; V_I = \text{GND or } V_{CC}; I_O = 0 \text{ A}$				
		outputs HIGH-state	-	0.04	0.1	mA
		outputs LOW-state	-	2.3	4.5	mA
		outputs disabled [5]		0.04	0.1	mA
ΔI _{CC}	additional supply current	per input pin; V_{CC} = 2.3 V to 2.7 V; [6] one input at V_{CC} - 0.6 V; other inputs at V_{CC} or GND	-	0.04	0.4	mA
Cı	input capacitance	V _I = 0 V or V _{CC}	-	3	-	pF
Co	output capacitance	V _O = 0 V or V _{CC}	-	9	-	pF
V _{CC} = 3.3	3 V ± 0.3 V					
V _{IK}	input clamping voltage	V _{CC} = 3.0 V; I _{IK} = -18 mA	-	-0.85	-1.2	V
V _{IH}	HIGH-level input voltage		2.0	-	-	V
V _{IL}	LOW-level input voltage		-	-	0.8	V
V _{OH}	HIGH-level output voltage	$V_{CC} = 3.0 \text{ V to } 3.6 \text{ V; } I_{O} = -100 \mu\text{A}$	V _{CC} - 0.2	V _{CC}	-	V
		V _{CC} = 3.0 V; I _O = -32 mA	2.0	2.3	-	V
V _{OL}	LOW-level output voltage	V _{CC} = 3.0 V				
		Ι _Ο = 100 μΑ	-	0.07	0.2	V
		I _O = 16 mA	-	0.25	0.4	V
		I _O = 32 mA	-	0.3	0.5	V
		I _O = 64 mA	-	0.4	0.55	V
V _{OL(pu)}	power-up LOW-level output voltage	$V_{CC} = 3.6 \text{ V}; I_O = 1 \text{ mA}; V_I = V_{CC} \text{ or GND}$ [2]	-	-	0.55	V

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Symbol	Parameter	Conditions		Min	Typ[1]	Max	Unit
l _l	input leakage current	all input pins;					
		V _{CC} = 0 V or 3.6 V; V _I = 5.5V		-	0.1	10	μA
		control pins					
		V_{CC} = 3.6 V; V_I = V_{CC} or GND		-	0.1	±1	μA
		data pins;					
		V _{CC} = 3.6 V; V _I = V _{CC}	-	0.5	1	μA	
		V _{CC} = 3.6 V; V _I = 0 V		-	0.1	-5	μA
I _{OFF}	power-off leakage current	$V_{CC} = 0 \text{ V}; V_{I} \text{ or } V_{O} = 0 \text{ V to } 4.5 \text{ V}$		-	0.1	±100	μΑ
I _{BHL}	bus hold LOW current	data inputs; V _{CC} = 3 V; V _I = 0.8 V		75	130	-	μA
I _{BHH}	bus hold HIGH current	data inputs; V _{CC} = 3 V; V _I = 2.0 V		-75	-140	-	μA
I _{BHLO}	bus hold LOW overdrive current	data inputs; V _{CC} = 3.6 V; V _I = 0 V to 3.6 V	[7]	500	-	-	μΑ
I _{внно}	bus hold HIGH overdrive current	data inputs; V _{CC} = 3.6 V; V _I = 0 V to 3.6 V	[7]	-500	-	-	μΑ
I _{EX}	external current	output in HIGH-state when $V_O > V_{CC}$; $V_O = 5.5 \text{ V}$; $V_{CC} = 3.0 \text{ V}$			10	125	μΑ
I _{O(pu/pd)}	power-up/power-down output current	$V_{CC} \le 1.2 \text{ V}; V_O = 0.5 \text{ V to } V_{CC};$ $V_I = \text{GND or } V_{CC}; \text{ n} \overline{\text{OE}} = \text{don't care}$	[8]	-	1	±100	μΑ
l _{OZ}	OFF-state output current	V_{CC} = 3.6 V; V_I = V_{IL} or V_{IH}					
		output HIGH-state; V _O = 3.0 V		-	0.5	5	μA
		output LOW-state; V _O = 0.5 V		-	0.5	-5	μA
I _{CC}	supply current	$V_{CC} = 3.6 \text{ V}; V_I = \text{GND or } V_{CC}; I_O = 0 \text{ A}$					
		outputs HIGH-state		-	0.07	0.1	mA
		outputs LOW-state		-	5.1	7	mA
		outputs disabled	[5]	-	0.07	0.1	mA
ΔI _{CC}	additional supply current	per input pin; V_{CC} = 3 V to 3.6 V; one input at V_{CC} - 0.6 V; other inputs at V_{CC} or GND	[6]	-	0.04	0.4	mA
Cı	input capacitance	V _I = 0 V or V _{CC}		-	3	-	pF
Co	output capacitance	V _O = 0 V or V _{CC}		-	9	-	pF

^[1] All typical values for V_{CC} = 2.5 V ± 0.2 V are measured at V_{CC} = 2.5 V and T_{amb} = 25 °C. All typical values for V_{CC} = 3.3 V ± 0.3 V are measured at V_{CC} = 3.3 V and T_{amb} = 25 °C.

- [2] For valid test results, data must not be loaded into the flip-flops (or latches) after applying power.
- [3] Unused pins at V_{CC} or GND.
- This parameter is valid for any V_{CC} between 0 V and 1.2 V with a transition time of up to 10 ms. From $V_{CC} = 1.2$ V to (2.5 ± 0.2) V a transition time of 100 μ s is permitted. This parameter is valid for $T_{amb} = 25$ °C only.
- [5] I_{CC} with outputs disabled is measured with outputs pulled to V_{CC} or GND.
- [6] This is the increase in supply current for each input at the specified voltage level other than V_{CC} or GND.
- [7] This is the bus hold overdrive current required to force the input to the opposite logic state.
- [8] This parameter is valid for any V_{CC} between 0 V and 1.2 V with a transition time of up to 10 ms. From V_{CC} = 1,2 V to (3.3 ± 0.3) V a transition time of 100 μ s is permitted. This parameter is valid for T_{amb} = 25 °C only.

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10. Dynamic characteristics

Table 7. Dynamic characteristics

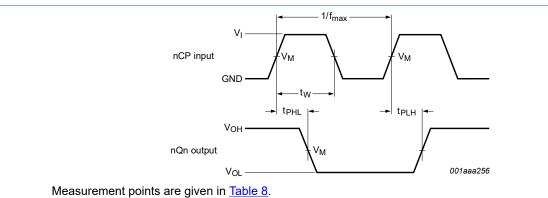
Voltages are referenced to GND (ground = 0 V); T_{amb} = -40 °C to +85 °C; for test circuit see Fig. 9.

Symbol	Parameter	Conditions	Min	Typ[1]	Max	Unit
V _{CC} = 2.	5 V ± 0.2 V					
t _{PLH}	LOW to HIGH propagation delay	nCP to nQn; see Fig. 6	1.0	4.4	7.0	ns
t _{PHL}	HIGH to LOW propagation delay	nCP to nQn; see Fig. 6	1.0	3.8	6.4	ns
t _{PZH}	OFF-state to HIGH propagation delay	nOE to nQn; see Fig. 8	1.5	4.6	7.5	ns
t _{PZL}	OFF-state to LOW propagation delay	nOE to nQn; see Fig. 8	1.0	2.8	4.6	ns
t _{PHZ}	HIGH to OFF-state propagation delay	nOE to nQn; see Fig. 8	1.5	3.5	5.5	ns
t _{PLZ}	LOW to OFF-state propagation delay	nOE to nQn; see Fig. 8	1.0	3.7	5.7	ns
t _{su}	set-up time	nDn to nCP HIGH; see Fig. 7	1.5	0.1	-	ns
		nDn to nCP LOW; see Fig. 7	2.0	0.5	-	ns
t _h	hold time	nDn to nCP HIGH; see Fig. 7	0.3	-0.5	-	ns
		nDn to nCP LOW; see Fig. 7	0.5	-0.1		ns
t _W	pulse width	nCP HIGH or LOW; see Fig. 6	1.5	-	-	ns
f _{max}	maximum frequency	nCP; see Fig. 6	150	-	-	MHz
V _{CC} = 3.	3 V ± 0.3 V					
t _{PLH}	LOW to HIGH propagation delay	nCP to nQn; see Fig. 6	1.0	3.2	5.0	ns
t _{PHL}	HIGH to LOW propagation delay	nCP to nQn; see Fig. 6	1.0	3.2	4.7	ns
t _{PZH}	OFF-state to HIGH propagation delay	nOE to nQn; see Fig. 8	1.0	3.4	5.6	ns
t _{PZL}	OFF-state to LOW propagation delay	nOE to nQn; see Fig. 8	0.5	2.3	3.7	ns
t _{PHZ}	HIGH to OFF-state propagation delay	nOE to nQn; see Fig. 8	1.5	3.7	5.4	ns
t _{PLZ}	LOW to OFF-state propagation delay	nOE to nQn; see Fig. 8	1.5	3.0	4.3	ns
t _{su}	set-up time	nDn to nCP HIGH or LOW; see Fig. 7	1.5	0.1	-	ns
t _h	hold time HIGH	nDn to nCP HIGH or LOW; see Fig. 7	0.5	0.1	-	ns
t _W	pulse width	nCP HIGH or LOW; see Fig. 6	1.5	-	-	ns
f _{max}	maximum frequency	nCP; see Fig. 6	150	-	-	MHz

^[1] All typical values for V_{CC} = 2.5 V \pm 0.2 V are measured at V_{CC} = 2.5 V and T_{amb} = 25 °C. All typical values for V_{CC} = 3.3 V \pm 0.3 V are measured at V_{CC} = 3.3 V and T_{amb} = 25 °C.

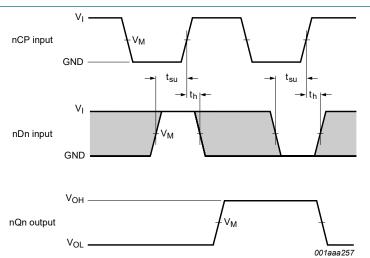
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10.1. Waveforms and test circuit



 V_{OL} and V_{OH} are typical voltage output levels that occur with the output load.

Fig. 6. Propagation delay clock input (nCP) to output (nQn), clock pulse (nCP) width and maximum clock frequency



Measurement points are given in Table 8.

 V_{OL} and V_{OH} are typical voltage output levels that occur with the output load.

The shaded areas indicate when the input is permitted to change for predictable output performance.

Fig. 7. Set-up times and hold times from input (nDn) to clock (nCP)

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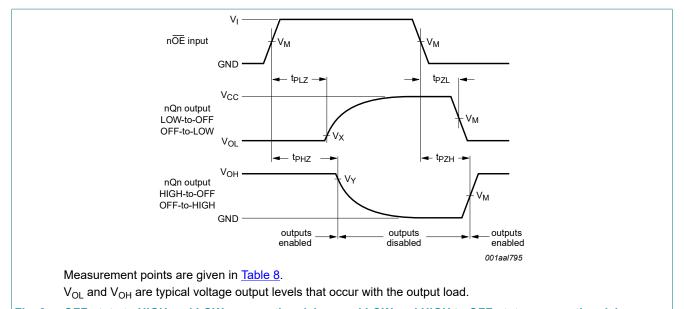
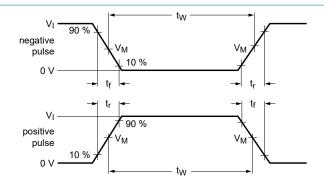


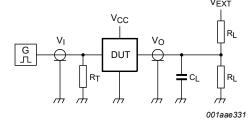
Fig. 8. OFF-state to HIGH and LOW propagation delays and LOW and HIGH to OFF-state propagation delays

Table 8. Measurement points

V _{cc}	Input		Output					
	V _I V _M		V _M	V _X	V _Y			
V _{CC} ≤ 2.7 V	V _{CC}	0.5 x V _{CC}	0.5 x V _{CC}	V _{OL} + 0.15 V	V _{OH} - 0.15 V			
V _{CC} ≥ 3.0 V	3.0 V	1.5 V	1.5 V	V _{OL} + 0.3 V	V _{OH} - 0.3 V			

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Test data is given in Table 9.

Definitions test circuit:

R_L = Load resistance;

C_L = Load capacitance including jig and probe capacitance;

R_T = Termination resistance should be equal to output impedance Z_o of the pulse generator;

 V_{EXT} = Test voltage for switching times.

Fig. 9. Test circuit for measuring switching times

Table 9. Test data

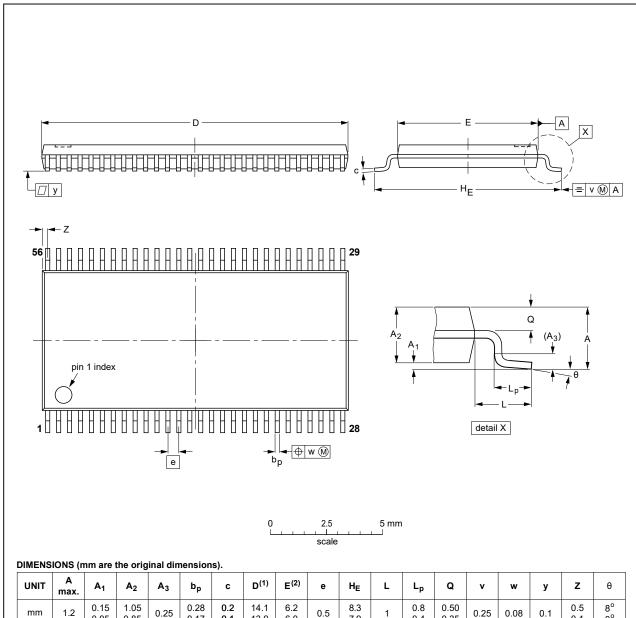
Input				Load		V _{EXT}			
V _I f _i		t _W	t _r , t _f	CL	R _L		t _{PLZ} , t _{PZL}	t _{PLH} , t _{PHL}	
3.0 V or V _{CC} whichever is less	≤ 10 MHz	500 ns	≤ 2.5 ns	50 pF	500 Ω	GND	6 V or V _{CC} x 2	open	

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11. Package outline

TSSOP56: plastic thin shrink small outline package; 56 leads; body width 6.1 mm

SOT364-1



UNIT	A max.	A ₁	A ₂	A ₃	bp	С	D ⁽¹⁾	E ⁽²⁾	е	HE	L	Lp	Q	٧	w	у	Z	θ
mm	1.2	0.15 0.05	1.05 0.85	0.25	0.28 0.17	0.2 0.1	14.1 13.9	6.2 6.0	0.5	8.3 7.9	1	0.8 0.4	0.50 0.35	0.25	0.08	0.1	0.5 0.1	8° 0°

Notes

- 1. Plastic or metal protrusions of 0.15 mm maximum per side are not included.
- 2. Plastic interlead protrusions of 0.25 mm maximum per side are not included.

OUTLINE VERSION	REFERENCES			EUROPEAN	ISSUE DATE	
	IEC	JEDEC	JEITA		PROJECTION	ISSUE DATE
SOT364-1		MO-153				99-12-27 03-02-19

Fig. 10. Package outline SOT364-1 (TSSOP56)

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12. Abbreviations

Table 10. Abbreviations

Acronym	Description
ANSI	American National Standards Institute
BiCMOS	Bipolar Complementary Metal Oxide Semiconductor
CDM	Charged Device Model
DUT	Device Under Test
ESD	ElectroStatic Discharge
ESDA	ElectroStatic Discharge Association
НВМ	Human Body Model
JEDEC	Joint Electron Device Engineering Council

13. Revision history

Table 11. Revision history

Document ID	Release date	Data sheet status	Change notice	Supersedes			
74ALVT162821 v.6	20240625	Product data sheet	-	74ALVT162821 v.5			
Modifications:	Section 2: E	<u>Section 2</u> : ESD specification updated according to the latest JEDEC standard.					
74ALVT162821 v.5	20201019	Product data sheet	-	74ALVT162821 v.4			
Modifications:	• <u>Section 1</u> a	 Type number 74ALVT162821DGG (SOT371-1 / SSOP56) removed. Section 1 and Section 2 updated. Table 4: Derating values for P_{tot} total power dissipation updated. 					
74ALVT162821 v.4	20180124	Product data sheet	-	74ALVT162821 v.3			
Modifications:	guidelines o	 The format of this data sheet has been redesigned to comply with the identity guidelines of Nexperia. Legal texts have been adapted to the new company name where appropriate. 					
74ALVT162821 v.3	19981002	Product data sheet	-	74ALVT162821 v.2			
74ALVT162821 v.2	19980213	Product specification	-	74ALVT162821 v.1			
74ALVT162821 v.1	19971117	Product specification	-	-			

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14. Legal information

Data sheet status

Document status [1][2]	Product status [3]	Definition	
Objective [short] data sheet	Development	This document contains data from the objective specification for product development.	
Preliminary [short] data sheet	Qualification	This document contains data from the preliminary specification.	
Product [short] data sheet	Production	This document contains the product specification.	

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20-bit bus interface D-type flip-flop; positive-edge trigger with 30 Ω termination resistors; 3-state

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